

Data sheet acquired from Harris Semiconductor SCHS044C – Revised September 2003

CMOS Low-Power Monostable/Astable Multivibrator

High Voltage Types (20-Volt Rating)

actable multivibrator with logic techniques incorporated to permit positive or negative edge-triggered monostable multivibrator action with retriggering and external counting options.

Inputs include +TRIGGER, -TRIGGER, ASTABLE, ASTABLE, RETRIGGER, and EXTERNAL RESET. Buffered outputs are \overline{Q} , Q, and OSCILLATOR. In all modes of operation, and external capacitor must be connected between C-Timing and RC-Common terminals, and an external resistor must be connected between the R-Timing and RC-Common terminals.

Astable operation is enabled by a high level on the ASTABLE input or a low level on the ASTABLE input, or both. The period of the square wave at the Q and Q Outputs in this mode of operation is a function of the external components employed. "True" input pulses on the ASTABLE input or "Complement" pulses on the ASTABLE input allow the circuit to be used as a gatable multivibrator. The OSCILLATOR output period will be half of the Q terminal output in the astable mode. However, a 50% duty cycle is not guaranteed at this output.

The CD4047B triggers in the monostable mode when a positive-going edge occurs on the +TRIGGER-input while the -TRIGGER is held low. Input pulses may be of any duration relative to the output pulse.

If retrigger capability is desired, the RETRIGGER input is pulsed. The retriggerable mode of operation is limited to positive-going edge. The CD4047B will retrigger as long as the RETRIGGER-input is high, with or without transitions (See Fig. 34).

An external countdown option can be implemented by coupling "Q" to an external "N" counter and resetting the counter with the trigger pulse. The counter output pulse is fed back to the ASTABLE input and has a duration equal to N times the period of the multivibrator.

A high level on the EXTERNAL RESET input assures no output pulse during an "ON" power condition. This input can also be activated to terminate the output pulse at any time. For monostable operation, whenever V_{DD} is applied, an internal power-on reset circuit will clock the Q output low within one output period (t_M).

The CD4047B-Series types are supplied in 14-lead hermetic dual-in-line ceramic packages (F3A suffix), 14-lead dual-in-line plastic packages (E suffix), 14-lead small-outline packages (M, MT, M96, and NSR suffixes), and 14-lead thin shrink small-outline packages (PW and PWR suffixes).

CD4047B Types

Features:

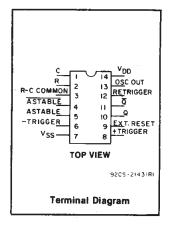
- Low power consumption: special CMOS oscillator configuration
- Monostable (one-shot) or a stable (free-running) operation
- True and complemented buffered outputs
- Only one external R and C required
- Buffered inputs
- 100% tested for quiescent current at 20 V
- Standardized, symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Monostable Multivibrator Features:

- Positive- or negative-edge trigger
- Output pulse width independent of trigger pulse duration
- Retriggerable option for pulse width expansion
- Internal power-on reset circuit
- Long pulse widths possible using small RC components by means of external counter provision
- Fast recovery time essentially independent of pulse width
- Pulse-width accuracy maintained at duty cycles approaching 100%

Astable Multivibrator Features:

- Free-running or gatable operating modes
- 50% duty cycle



- Oscillator output available
- Good astable frequency stability: Frequency deviation:

= $\pm 2\% + 0.03\%$ /°C @ 100 kHz = $\pm 0.5\% + 0.015\%$ /°C @ 10 kHz (circuits "trimmed" to frequency $V_{DD} = 10 \text{ V} \pm 10\%$)

Applications:

Digital equipment where low-power dissipation and/or high noise immunity are primary design requirements:

- Envelope detection
- Frequency multiplication
- Frequency division
- Frequency discriminators
- Timing circuits
- Time-delay applications

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIN	UNITS			
	MIN.	MAX.	UNHS		
Supply-Voltage Range (For T _A = Full Package-Temperature Range)	3	18	٧		
NOTE: IF AT 15 V OPERATION A 10 MΩ RESISTOR IS USED THE OPERATING TEMPERATURE SHOULD BE BETWEEN -25°C and 100°C					

MAXIMUM RATINGS, Absolute-Maximum Values:

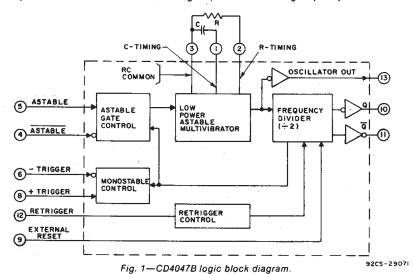
DC SUPPLY-VOLTAGE RANGE, (VDD)
Voltages referenced to V _{SS} Terminal)0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS0.5V to VDD +0.5V
DC INPUT CURRENT, ANY ONE INPUT
POWER DISSIPATION PER PACKAGE (PD):
For T _A = -55°C to +100°C
For T _A = +100°C to +125°C
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)
OPERATING-TEMPERATURE RANGE (TA)55°C to +125°C
STORAGE TEMPERATURE RANGE (T _{stq})65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max

CD4047B Types

CD4047B FUNCTIONAL TERMINAL CONNECTIONS NOTE: IN ALL CASES EXTERNAL RESISTOR BETWEEN TERMINALS 2 AND 3^A EXTERNAL CAPACITOR BETWEEN TERMINALS 1 AND 3^A

		AL CONNE	CTIONS	OUTPUT	OUTPUT PERIOD
FUNCTION	TO VDD TO VSS		INPUT TO	PULSE FROM	OR PULSE WIDTH
Astable Multivibrator:					
Free Running	4,5,6,14	7,8,9,12	_	10,11,13	$t_A (10,11) = 4.40 \text{RC}$
True Gating	4,6,14	7,8,9,12	5	10,11,13	$t_A^{(13)} = 2.20 \text{ RC}^{\#}$
Complement Gating	6,14	5,7,8,9,12	4	10,11,13	^ ` ′
Monostable Multivibrator:					
Positive-Edge Trigger	4,14	5,6,7,9,12	8	10,11	1
Negative-Edge Trigger	4,8,14	5,7,9,12	6	10,11	t_{M} (10,11) = 2.48 RC
Retriggerable	4,14	5,6,7,9	8,12	10,11	,
External Countdown*	14	5,6,7,8,9,12		10,11	

- ▲ See Text.
- # First positive ½ cycle pulse-width = 2.48 RC, see Note on Page 3-134.
- * Input Pulse to Reset of External Counting Chip External Counting Chip Output To Terminal 4



ASTABLE (3)

ASTABLE (4)

+TRIGGER (8)

-TRIGGER (8)

-TRIGGER (8)

-TRIGGER (8)

-TRIGGER (9)

-TRIGGER (10)

Fig. 2—CD4047B logic diagram.

CD4047B Types

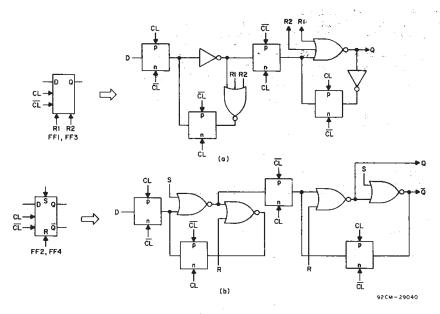


Fig. 3—Detail logic diagram for flip-flops FF1 and FF3 (a) and for flip-flops FF2 and FF4 (b).

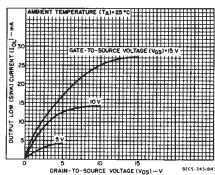


Fig. 4—Typical output low (sink) current characteristics.

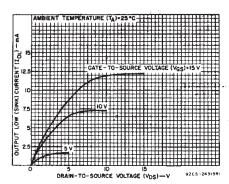


Fig. 5—Minimum output low (sink) current characteristics.

STATIC ELECTRICAL CHARACTERISTICS

CHARAC- TERIS-	co	NDITIO	NS	LIMITS AT INDICATED TEMPERATURES (°C)							
TICS	vo	VIN	VDD					+ 25			UNITS
	(v)	(V)	(V)	-55	-40	+85	+ 125	Min.	Тур.	Max.	
Quiescent	_	0,5	5	1	1	30	30	_	0.02	1	
Device Cur-		0,10	10	2	2	60	60	_	0.02	2	1
rent, I _{DD}	_	0,15	15	4	4	120	120	_	0.02	4	μΑ
Max.	<u> </u>	0,20	20	20	20	600	600		0.04	20	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	_	
(Sink)	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6		
Current IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	_	mA
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	1
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	_	1
Current,	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	<u> </u>	
I _{OH} Min.	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	_]
Output Volt-	-	0,5	5	0.05		_	0	0.05			
age: Low-		0,10	10	L	0.0)5			0	0.05	lv
Level V _{OL} Max.		0,15	15	0.05 - 0					0.05	V	

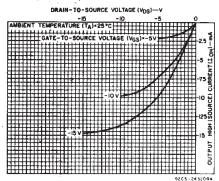


Fig. 6—Typical output high (source) current characteristics.

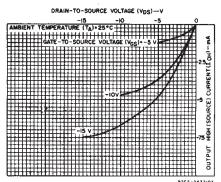


Fig. 7—Minimum output high (source) current characteristics.

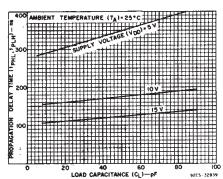


Fig. 8—Typical propagation delay time as a function of load capacitance (Astable, Astable to Q, Q).

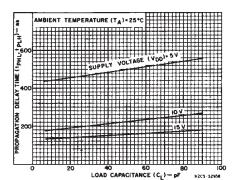


Fig. 9—Typical propagation delay time as a function of load capacitance (+ or – trigger to Q, Q).

STATIC ELECTRICAL CHARACTERISTICS (CONTINUED)

CHARAC- TERIS-	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							
TICS	v _o	V _{IN}	VDD						UNITS		
	(V)	(V)	(V)	-55	-40	+ 85	+ 125	Min.	Тур.	Max.]
Output Volt-		0.5	5		4.95				5	_	
age: High-		0,10	10		9.9)5		9.95	10	_	1
Level, V _{OH} Min.	_	0,15	15	, ,	14.	95		14.95	15	-	V
Input Low	0.5,4.5		5	1.5			_		1.5		
Voltage, V _{IL}	1,9	_	10		3					3	1
Max.	1.5,13.5	_	15		4			_		4	l v l
Input High	0.5,4.5	_	5		3.	5		3.5	_		1 '
Voltage,	1.9		10	7		7		7		_	1
V _{IH} Min.	1.5,13.5	_	15		11				_	_	
Input Cur- rent I _{IN} Max.	_	0,18	18	± 0.1	± 0.1	±1	±1	_	± 10 ⁵	±0.1	μΑ

DYNAMIC ELECTRICAL CHARACTERISTICS at TA = 25°C; Input t, t = 20 ns,

$C_1 = 50 pF$, $R_1 = 200 kQ$

CHARACTERISTIC	V _{DD} (V)		LIMITS		UNITS
	DD ()	MIN.	TYP.	MAX.	UNITS
Propagation Delay Time, teht, teth	5		200	400	
Astable, Astable to Osc. Out	10	_	100	200	
	15	-	80	160	
	5		350	700	i
Astable, Astable to Q, Q	10	_	. 175	350	
	15	_	125	250	
	5		500	1000	1 :
+ or - Trigger to Q, Q	10	<u> </u>	225	450	
	15	_	150	300	
	5		300	600	1
Retrigger to Q, Q	10	-	150	300	1
	15	–	100	200	
	5	 	250	500	1
External Reset to Q, Q	10	–	100	200	ns
	15	-	70	140	
Transition Time, t _{THL} , t _{TLH}	5		100	200	1
Osc. Out, Q, Q	10	— .	50	100	
•	15	-	40	80	
Minimum Input Pulse	5		200	400	1
Width, tw	10	_	80	160	1
+ Trigger, - Trigger	15	_	. 50	100	
	5	_	100	200	1
Reset	10		50	100	
	15	-	30	60	
	5	_	300	600	1
Retrigger	10	-	115	230	ŀ
	15	_	75	150	
Input Rise and Fall Time, t,tr		1			
All Trigger Inputs		1			
For + Trigger: t _f	5	-	270	_	1
t _r only is unlimited	10	_	18	-	
	15	_	9	-	μs
For - Trigger: t,	5		325	_	1
t _f only is unlimited	10		9	_	1
	15	_	4	_	1
Q or Q Deviation from 50%	5		±0.5	±1	
Duty Factor	10	_	±0.5	±1	%
	15	_	±0.1	±0.5	1
Input Capacitance, CIN	Any Input	<u> </u>	5	7.7	pF

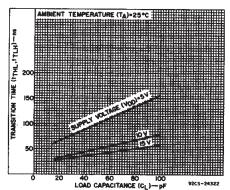


Fig. 10—Typical transition time as a function of load capacitance.

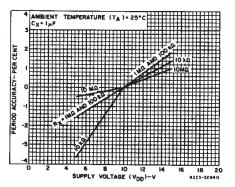


Fig. 11—Typical astable oscillator or Q, Q period accuracy vs. supply voltage.

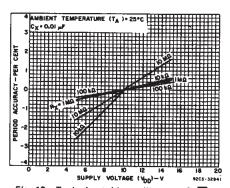


Fig. 12—Typical astable oscillator or Q, Q period accuracy vs. supply voltage.

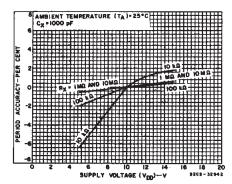


Fig. 13—Typical astable oscillator or Q, \overline{Q} period accuracy vs. supply voltage.

CD4047B Types

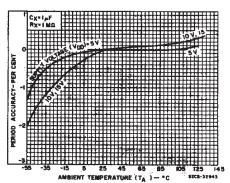


Fig. 14—Typical astable oscillator or Q, Q period accuracy vs. ambient temperature (ultra-low frequency).

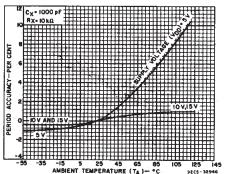


Fig. 17—Typical astable oscillator or Q, Q period accuracy vs. ambient temperature (high-frequency).

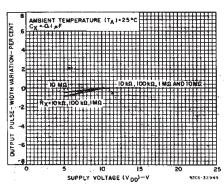


Fig. 20—Typical output pulse-width variations vs. supply voltage.

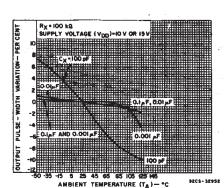


Fig. 23—Typical output pulse-width variations vs. ambient temperature.

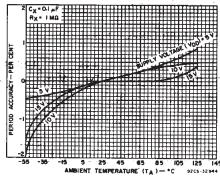


Fig. 15—Typical astable oscillator or Q, Q period accuracy vs. ambient temperature (low frequency).

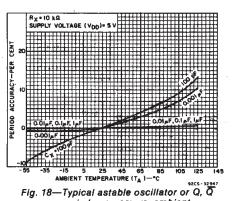


Fig. 18—Typical astable oscillator or Q, (period accuracy vs. ambient temperature.

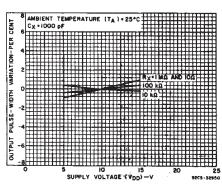


Fig. 21—Typical output pulse-width variations vs. supply voltage.

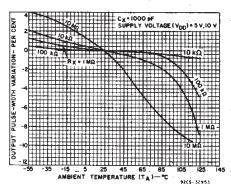


Fig. 24—Typical output-pulse-width variations vs. ambient temperature.

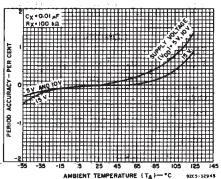


Fig. 16—Typical astable oscillator or Q, Q period accuracy vs. ambient temperature (medium frequency).

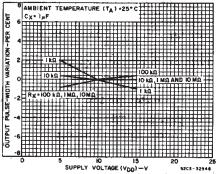


Fig. 19—Typical output pulse-width variations vs. supply voltage.

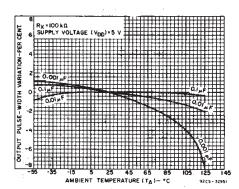


Fig. 22—Typical output pulse-width variations vs. ambient temperature.

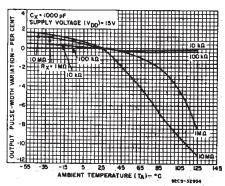


Fig. 25—Typical output pulse-width variations vs. ambient temperature.

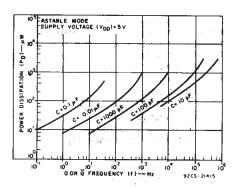


Fig. 26—Typical power dissipation vs. output frequency ($V_{DD} = 5 V$).

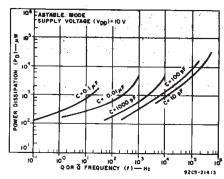


Fig. 27—Typical power dissipation vs. output frequency ($V_{DD} = 10 \text{ V}$).

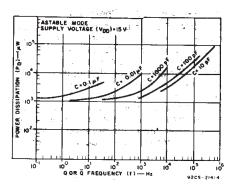


Fig. 28—Typical power dissipation vs. output frequency ($V_{DD} = 15 \text{ V}$).

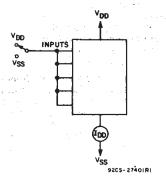


Fig. 29-Quiescent device current test circuit.

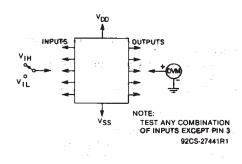


Fig. 30-Input-voltage test circuit.

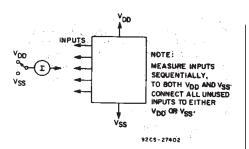


Fig. 31—Input-leakage-current test circuit

1. Astable Mode Design Information

A. Unit-to-Unit Transfer-Voltage Variations - The following analysis

presents variations from unit to unit as a function of transfer-voltage (V_{TR}) shift (33% -67% V_{DD}) for free-running (astable) operation.

Fig. 32-Astable mode waveforms

$$t_1 = -RC \ln \frac{V_{TR}}{V_{DD} + V_{TR}};$$

$$typically, t_1 = 1.1 RC$$

$$t_2 = -RC \ln \frac{V_{DD} - V_{TR}}{2V_{DD} - V_{TR}};$$

$$typically, t_2 = 1.1 RC$$
 $t_A = 2(t_1 + t_2)$

$$= -2 RC \ln \frac{(V_{TR})(V_{DD} - V_{TR})}{(V_{DD} + V_{TR})(2V_{DD} - V_{TR})}$$

thus if $t_A=4.40\,RC$ is used, the variation will be +5%, -0% due to variations in transfer voltage.

B. Variations Due to V_{DD} and Temperature Changes — In addition to variations from unit to unit, the astable period varies with V_{DD} and temperature. Typical variations are presented in graphical form in Figs. 11 to 16 with 1037 as reference for voltage variations curves and 25°C as reference for temperature variations curves.

II. Monostable Mode Design Information The following analysis presents variations from unit to unit as a function of transfer-voltage (VTR) shift (33% - 67% V_{DD}) for one-shot (monostable) operation.

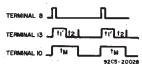


Fig. 33-Monostable waveforms.

$$t_{1'} = -RC \ln \frac{V_{TR}}{2V_{DD}}$$

typically, t₁' = 1.38 RC

$$t_{M} = (t_{1}r_{+} t_{2})$$
 (VTP)

$$t_{M} = -RC \text{ In } \frac{(V_{TR})(V_{DD} - V_{TR})}{(2V_{DD} - V_{TR})(2V_{DD})}$$

where $t_{\mbox{\scriptsize M}}=\mbox{\scriptsize Monostable mode pulse}$ width. Values for $t_{\mbox{\scriptsize M}}$ are as follows:

Typ: $V_{TR} = 0.5 V_{DD}$ $t_{M} = 2.48 RC$ Min: $V_{TR} = 0.33 V_{DD}$ t_M = 2.71 RC Max: $V_{TR} = 0.67 V_{DD}$

thus is $t_{M}=2.48\,\mathrm{RC}$ is used, the variation will be $+9.3\%,\ -0\%$ due to variations in transfer voltage.

In the astable mode, the first positive half cycle has a duration of t_M; succeeding durations are tA/2.

In addition to variations from unit to unit. the monostable pulse width varies with VDD and temperature. These variations are presented in graphical form in Fig. 19 to 26 with 10 V as reference for voltagevariation curves and 25°C as reference for temperature-variation curves.

III. Retrigger Mode Operation

+TRIGGER & RETRIGGER

TERMINALS 8 & 12 OSC OUTPUT TERMINAL 13

Q OUTPUT TERMINAL IO

The CD4047B can be used in the retrigger mode to extend the output-pulse duration, or to compare the frequency of an input signal with that of the internal oscillator. In the retrigger mode the input pulse is applied to terminal 12, and the output is taken from terminal 10 or 11. As shown in Fig. 34 normal monostable action is obtained when one retrigger pulse is applied. Extended pulse duration is obtained when more than one pulse is applied.

┅... -┅-

larger than the CMOS "ON" resistance in series with it, which typically is hundreds of ohms. In addition, with very large values of R, some short-term instability with respect to time may be noted.

The recommended values for these components to maintain agreement with



Fig. 34-Retrigger-mode waveforms.

†RE

¹RE ...

For two input pulses, $t_{RE} = t_1' + t_1 + 2t_2$. For more than two pulses, the output pulse width is an integral number of time periods, with the first time period being t₁' + t₂, typically, 2.48RC, and all subsequent time periods being t1 + t2, typically, 2.2RC.

TRE__

IV. External Counter Option

Time t_M can be extended by any amount with the use of external counting cir-

cuitry. Advantages include digitally controlled pulse duration, small timing capacitors for long time periods, and extremely fast recovery time. A typical implementation is shown in Fig. 35. The pulse duration at the output is

$$t_{ext} = (N - 1)(t_A) + (t_M + t_A/2)$$

where $t_{\mbox{ext}} = \mbox{pulse}$ duration of the circuitry, and N is the number of counts used.

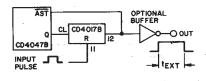


Fig. 35—Implementation of external counter. option.

9208-29041

V. Timing-Component Limitations

The capacitor used in the circuit should be non-polarized and have low leakage (i.e. the parallel resistance of the capacitor should be at least an order of magnitude greater than the external resistor used). There is no upper or lower limit for either R or C value to maintain oscillation.

However, in consideration of accuracy, C must be much larger than the inherent stray capacitance in the system (unless this capacitance can be measured and taken into account). R must be much

previously calculated formulas without trimming should be:

†RE

92C\$ ~ 2002 9RI

C ≥ 100 pF, up to any practical value, for astable modes;

C ≥ 1000 pF, up to any practical value for monostable modes.

10 kQ ≤ R ≤ 1 MQ

VI. Power Consumption

in the standby mode (Monostable or Astable), power dissipation will be a function of leakage current in the circuit, as shown in the static electrical characteristics. For dynamic operation, the power needed to charge the external timing capacitor C is given by the following formulae:

Astable Mode:

 $P = 2CV^2f$. (Output at terminal No. 13) P = 4CV²f. (Output at terminal Nos. 10 and 11)

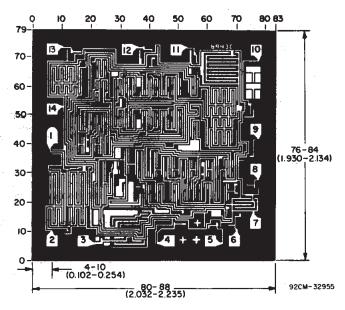
Monostable Mode:

$$P = \frac{(2.9CV^2) \text{ (Duty Cycle)}}{\overline{}}$$

(Output at terminal Nos. 10 and 11)

The circuit is designed so that most of the total power is consumed in the external components. In practice, the lower the values of frequency and voltage used, the closer the actual power dissipation will be to the calculated value.

Because the power dissipation does not depend on R, a design for minimum power dissipation would be a small value of C. The value of R would depend on the desired period (within the limitations discussed above). See Figs. 27, 28, and 29 for typical power consumption in astable mode.



Chip dimensions and pad layout for CD4047B

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10-3 inch).





i.com 28-Feb-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
8102001CA	ACTIVE	CDIP	J	14	1	None	Call TI	Level-NC-NC-NC
CD4047BD3	ACTIVE	CDIP SB	JD	14	1	None	Call TI	Level-NC-NC-NC
CD4047BE	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD4047BF	ACTIVE	CDIP	J	14	1	None	Call TI	Level-NC-NC-NC
CD4047BF3A	ACTIVE	CDIP	J	14	1	None	Call TI	Level-NC-NC-NC
CD4047BM	ACTIVE	SOIC	D	14	50	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD4047BM96	ACTIVE	SOIC	D	14	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD4047BMT	ACTIVE	SOIC	D	14	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD4047BNSR	ACTIVE	SO	NS	14	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD4047BPW	ACTIVE	TSSOP	PW	14	90	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
CD4047BPWR	ACTIVE	TSSOP	PW	14	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM

 $^{(1)}$ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

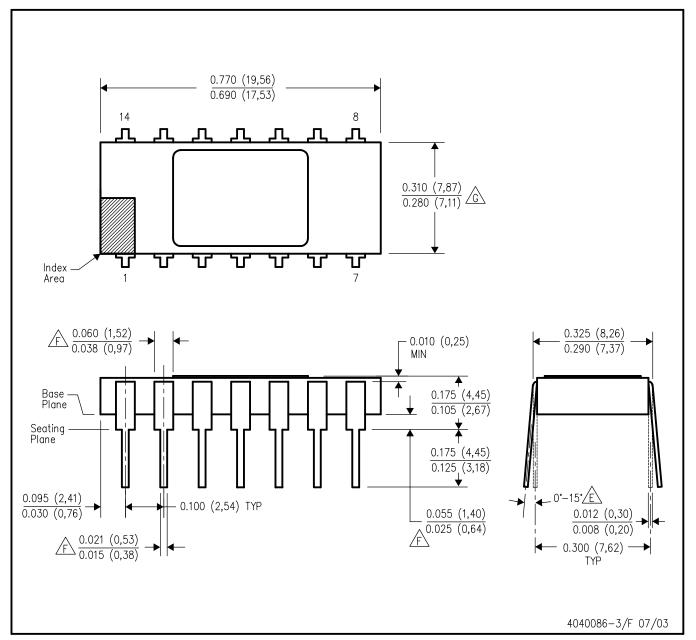
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

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JD (R-CDIP-T14)

CERAMIC SIDE-BRAZE DUAL-IN-LINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Controlling dimension: inch.
- D. Leads within 0.005 (0,13) radius of true position (TP) at gage plane with maximum material condition and unit installed.
- E Angle applies to spread leads prior to installation.
- F Outlines on which the seating plane is coincident with the plane (standoff = 0), terminals lead standoffs are not required, and lead shoulder may equal lead width along any part of the lead above the seating/base plane.
- G Body width does not include particles of packing materials.
- H. A visual index feature must be located within the cross—hatched area.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AB.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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